

Magic Numbers of Silicon Clusters

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Abstract

A structural model for intermediate sized silicon clusters is proposed that is able to generate unique structures without any dangling bonds. This structural model consists of bulk-like core of five atoms surrounded by fullerene-like surface. Reconstruction of the ideal fullerene geometry results in the formation of crown atoms surrounded by π -bonded dimer pairs. This model yields unique structures for Si_{33} , Si_{39} , and Si_{45} clusters without any dangling bonds and hence explains why these clusters are least reactive towards chemisorption of ammonia, methanol, ethylene, and water. This model is also consistent with the experimental finding that silicon clusters undergo a transition from prolate to spherical shapes at Si_{27} . Finally, reagent specific chemisorption reactivities observed experimentally is explained based on the electronic structures of the reagents.

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Smalley and co-workers carried out extensive studies on chemisorption of various reagents on intermediate sized silicon clusters [1]. These studies revealed that the reactivity rates for ammonia (NH_3) chemisorption vary by over three orders of magnitude as a function of cluster size, with 21, 25, 33, 39, and 45 atom clusters being particularly unreactive. Clusters containing more than forty seven atoms are highly reactive and they do not display strong oscillations in reactivities as a function of the cluster size. Similar results were obtained with methanol (CH_3OH), ethylene (C_2H_4), and water (H_2O). On the other hand, nitric oxide (NO) and oxygen (O_2) were found to react readily with all clusters in this size range.

Several structural models have been proposed to explain these experimental data [2–6]. However, these models do not yield unique and consistent structures for different cluster sizes and each cluster structure has to be obtained independently. Furthermore, these models do not satisfy the essential criterion that the structures of the unreactive clusters should not have any dangling bonds.

In this Letter we propose a consistent model that generates the structures of the intermediate sized unreactive silicon clusters in a systematic way. The structures thus generated are unique for Si_{33} , Si_{39} , and Si_{45} clusters. Furthermore, these clusters do not have any dangling bonds and hence explains why these clusters are unreactive for chemisorption. Finally, our model is consistent with the experimental finding of Jarrold and Constant that silicon clusters undergo a shape transition from prolate to spherical shapes at Si_{27} [7].

Our structural model for silicon clusters consists of bulk-like core of five atoms surrounded by fullerene-like surface. The core atoms bind to the twelve surface atoms, thus rendering them bulk-like with four-fold coordination. The surface then relaxes from its ideal fullerene geometry to give rise to crown atoms and dimer pairs. The crown atoms are called adatoms in surface science literature [8]. These crown atoms are formally three-fold coordinated and possess one dangling bond each. The dimer pairs are also formally three-fold coordinated, but they eliminate their dangling bonds through local π bonding. This model yields structures with seventeen four-fold coordinated atoms, four crown atoms, and the rest dimer pairs. The essential feature of this construction is that the bulk-like core and fullerene-like surface make these structures stable. This model is applicable to clusters containing more than twenty atoms.

Unlike carbon, silicon does not form strong delocalized π bonds. Consequently, fullerene cage structures [9,10], which require strong delocalized π bonds, are energetically unfavorable for silicon. For this reason, silicon clusters prefer as few surface atoms as possible. Nonetheless, the fullerene geometry for the surface, consisting of interlocking pentagons and hexagons, gives special stability to the surface atoms. Furthermore, since delocalized π bonding is not favorable in silicon, we expect the surface atoms to relax from their ideal fullerene geometry to allow for dimer formation through strong local π bonding. Our model accounts for all these facts.

The 5-atom core in our model has the exact structure of bulk silicon with one atom in the center bonded to four atoms arranged in a perfect tetrahedral symmetry. There are numerous ways to orient the 5-atom core inside the fullerene cage and bind it to the surface atoms. Furthermore, structural isomers may exist for fullerenes of any size [10,11]. Thus it is possible to use this model to generate all possible structural isomers for any odd numbered intermediate sized cluster. However, a particular orientation of the 5-atom core inside the fullerene cage will yield structures with maximum number of dimer pairs and least number

of dangling bonds. Such isomers are likely to be most stable.

The 28- and 40-atom fullerenes are the only ones belonging to the symmetry group T_d in the 20-60 atom size range [10]. We generate the Si_{33} and Si_{45} structures by inserting the 5-atom core inside the 28- and 40-atom fullerene, respectively. We orient the 5-atom pyramid in such a way that the central atom (A, violet), the apex atom (B, blue) of the pyramid, and the crown atom (C, red) on the surface lie on a line. The C atom is the central atom shared by three fused pentagons. This atom is surrounded by three other surface atoms (D, green), which relax inwards to bind to the four core atoms B. This relaxation motion is identical to that necessary to form the 2×1 reconstruction on the bulk $\text{Si}(111)$ surface [12,13]. With an activation barrier of only ≈ 0.01 eV [12,14] and gain of 2.3 eV/bond due to σ bond formation between B and D [13,15], such a relaxation of fullerene surface is feasible even at 100 K. Finally, the remaining surface atoms (E, orange) readjust to form as many dimers as possible. This relaxation is similar to that on $\text{Si}(100)$ surface yielding dimer pairs [13,16]. The dimers are σ -bonded pair of atoms whose dangling bonds are saturated through strong local π bonds. Because of the tetrahedral symmetry of the core as well as of the reconstructed fullerene cage, the final Si_{33} and Si_{45} structures also have tetrahedral symmetry. The Si_{39} structure is also generated in this way, starting from the 34-atom fullerene cage and stuffing five atoms inside it. However, the structure thus generated has only C_{3v} symmetry, because of the lower symmetry of the fullerene cage [10].

The Si_{33} , Si_{39} , and Si_{45} cluster structures thus generated are displayed in Fig. 1. These structures have seventeen four-fold coordinated atoms, four crown atoms, and variable number of dimer pairs. The Si_{33} structure has six dimer pairs, whereas Si_{45} has twelve dimer pairs forming four hexagons. On the other hand, the surface of the Si_{39} cluster consists of nine dimer pairs, three of which form a hexagon.

We constructed Si_{35} and Si_{43} clusters also using the proposed model, but found that these structures do not possess the characteristic crown-atom-dimer pattern found in unreactive clusters. Consequently, these structures possessed large number of dangling bonds. This explains the highly reactive nature of these clusters.

In principle, the proposed model can be used to construct Si_{25} structure also. However, Si_{20} cage is too small to accommodate five atoms inside it without undue strain. Consequently, Si_{25} will prefer a different geometry. Indeed, there is experimental evidence that clusters smaller than Si_{27} do not possess spherical shapes characteristic of larger clusters; instead they seem to prefer prolate shapes [7]. Our inability to generate a compact structure for Si_{25} explains this experimental observation also.

We verified our model by constructing structures of all the clusters discussed here using the molecular modelling kits [17]. These structures unambiguously demonstrated that only 33-, 39-, and 45-atom clusters possess the crown-atom-dimer pattern on their surfaces. We then calculated the atomic coordinates of these clusters from the tetrahedral geometry of the 5-atom core and the known geometries of the fullerene structures [10], assuming that all bond lengths are equal to the bulk value of 2.35 Å. The structures thus generated are displayed in Fig. 1. We then relaxed these structures by carrying out molecular dynamics at 100 K using the Kaxiras-Pandey potential [18]. The final structures obtained from these simulations are nearly identical to the initial ones. This indicates that the proposed structures are locally stable.

The computer generated structures displayed in Fig. 1 revealed that the crown atoms

are able to form a fourth bond to the core atoms B, thus rendering the B atoms formally five-fold coordinated. The B-C bond arises from the back donation of the electrons from C to B and it weakens the neighboring bonds through electronic repulsion. The dangling bond on the crown atom is thus eliminated and these magic number clusters become unreactive.

The classical potentials available at present [18,19] are most appropriate for bulk silicon and related structures. Such potentials may not be suitable for describing unusual bonding patterns, such as the five-fold coordinated silicon atoms found in these clusters. Consequently, we cannot use the available classical potentials to prove that the proposed structures correspond to the lowest energy structures. Finally, structural determination based on the first principles electronic structure calculations are extremely demanding computationally at present for such large clusters, especially if adequate basis sets and grid sizes are employed and the calculations are converged to better than 0.01 eV accuracy. Furthermore, such complicated calculations do not provide the conceptual framework for understanding cluster properties. On the other hand, our simple physically motivated stuffed fullerene model yields insights into the nature of bonding in silicon clusters and explains the experimental trends in reactivities.

There exist several competing structural models [2–6] of silicon clusters that attempt to explain the experimental reactivity data of Smalley and co-workers [1]. For example, Kaxiras has proposed structures of Si_{33} and Si_{45} clusters based on the reconstructed 7×7 and 2×1 surfaces of bulk Si(111), respectively [4]. However, this model does not explain the reactivity data since bulk surfaces are highly reactive. Furthermore, it is inconsistent that the surface of Si_{45} should be the metastable 2×1 surface rather than the more stable 7×7 surface [13]. Finally, the Si_{45} structure of Kaxiras has forty dangling bonds, which make it highly reactive, contrary to the experiments. To overcome this discrepancy between experiment and theory, Kaxiras has proposed that the dangling bonds on Si_{45} form π -bonded chains, analogous to the 2×1 reconstruction of the bulk Si(111) surface [20]. However, silicon favors strong local π bonds over delocalized π -bonded chains. This is the reason why the 2×1 reconstruction, involving π -bonded chains [20], is metastable with respect to the locally π -bonded 7×7 reconstruction on the bulk Si(111) surface [13]. For the same reason, the Si_{45} structure proposed by Kaxiras is a metastable and highly reactive structure. Indeed, Jelski and co-workers disputed the Kaxiras model of Si_{45} by constructing alternative structures for Si_{45} that are lower in energy, but do not possess any of the features of the reconstructed bulk surfaces [6].

The bonding characteristics of silicon differ in subtle ways from that of carbon. In carbon, delocalized π bonds are favored over local π bonds, whereas the opposite is true in silicon. For this reason, graphite is the most stable form of carbon at room temperature and atmospheric pressure, but not the graphite form of silicon. Likewise, the bulk (111) surface of the diamond form of carbon exhibits the 2×1 reconstruction, but not the 7×7 reconstruction [21,22]. These examples, illustrate how subtle differences in bonding characteristics determine possible crystal structures and surface reconstructions. The same is true of clusters and the models of cluster structures should account for these characteristics. Our model of silicon clusters accounts for these facts by focussing on structures that are able to form maximum number of σ bonds and eliminate their surface dangling bonds through local π bonding.

Our structure for Si_{33} is identical to that proposed by Kaxiras [4] and Patterson and

Messmer [5]. This structure has been shown to be locally stable [23]. But our Si_{45} structure is different from that of Kaxiras [4]. However, we can generate the Si_{45} structure of Kaxiras by stuffing one atom inside a 44-atom fullerene cage and allowing for the reconstruction of the fullerene surface. Thus our model is very general, subsuming the Kaxiras model within it.

The reactivity patterns of NO and O_2 are different from those found for NH_3 , CH_3OH , C_2H_4 , and H_2O [1]. This may be explained based on the ground state electronic structures of these reagents. NH_3 , CH_3OH , C_2H_4 , and H_2O in their ground states have closed shell electronic structure with all electrons paired. On the other hand, NO and O_2 in their ground states are $^2\Pi_g$ and $^3\Sigma_g^-$, possessing one and two unpaired electrons, respectively [24]. Consequently, NH_3 , CH_3OH , C_2H_4 , and H_2O can chemisorb only at those sites where excess electron density is present due to dangling bonds. Such a selectivity gives rise to highly oscillatory pattern in the reactivities, because the number of dangling bonds varies as a function of cluster size. The magic number clusters are unreactive because they do not possess any dangling bonds. On the other hand, NO ($^2\Pi_g$) and O_2 ($^3\Sigma_g^-$) can chemisorb anywhere, because these reagents carry the necessary dangling bonds for instigating the reaction anywhere on the cluster surface. Hence, NO and O_2 readily react with all clusters and do not display the oscillatory pattern in their chemical reactivities. This explains the reagent specific chemisorption reactivities observed experimentally [1].

The magic number clusters are not completely inert towards the closed shell reagents [1]. These clusters are more reactive towards NH_3 , CH_3OH , and H_2O than towards C_2H_4 . This is because NH_3 , CH_3OH , and H_2O have lone pairs on either nitrogen or oxygen and these lone pairs have a small probability of instigating reaction on the cluster surface. A lone pair is a pair of electrons that is not part of a bond. C_2H_4 does not have any lone pairs and hence the magic number clusters are quite unreactive towards this molecule. The electronic structure of reagents thus explains even subtle variations in the reactivities of magic number clusters towards a group of related reagents.

In summary, we propose a structural model for the unreactive silicon clusters containing more than twenty atoms. This model consists of bulk-like core of five atoms surrounded by reconstructed fullerene surface. The resulting structures for Si_{33} , Si_{39} , and Si_{45} are unique, have maximum number of four-fold coordinated atoms, minimum number of surface atoms, and zero dangling bonds. Such unique structures cannot be built for other intermediate sized clusters and hence they will have larger number of dangling bonds. This explains why Si_{33} , Si_{39} , and Si_{45} clusters are least reactive towards closed shell reagents ammonia, methanol, ethylene, and water [1]. Our model also indicates that Si_{25} cluster cannot be formed in a spherical shape. This result is consistent with the experimental finding that silicon clusters undergo a shape transition from prolate to spherical shapes at Si_{27} [7]. Finally, two distinct patterns of chemisorption reactivities observed experimentally are explained based on the electronic structures of the reagents. The reactivities of closed shell reagents depend on the available number of dangling bond sites, whereas the reactivities of free radical reagents are not so dependent. Consequently, only the closed shell reagents are sensitive to the cluster structure and hence exhibit the highly oscillatory pattern in reactivities as a function of the cluster size.

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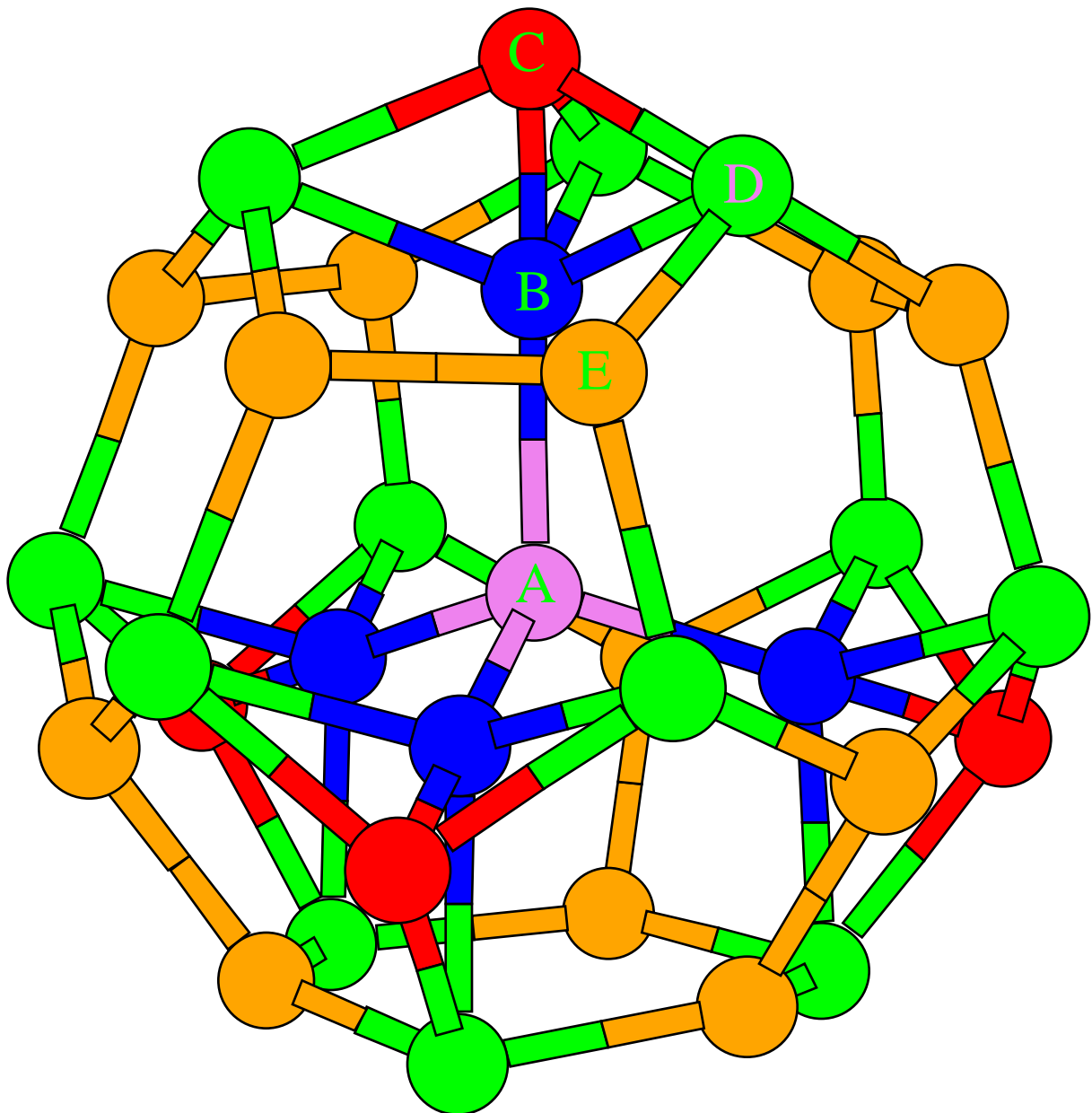
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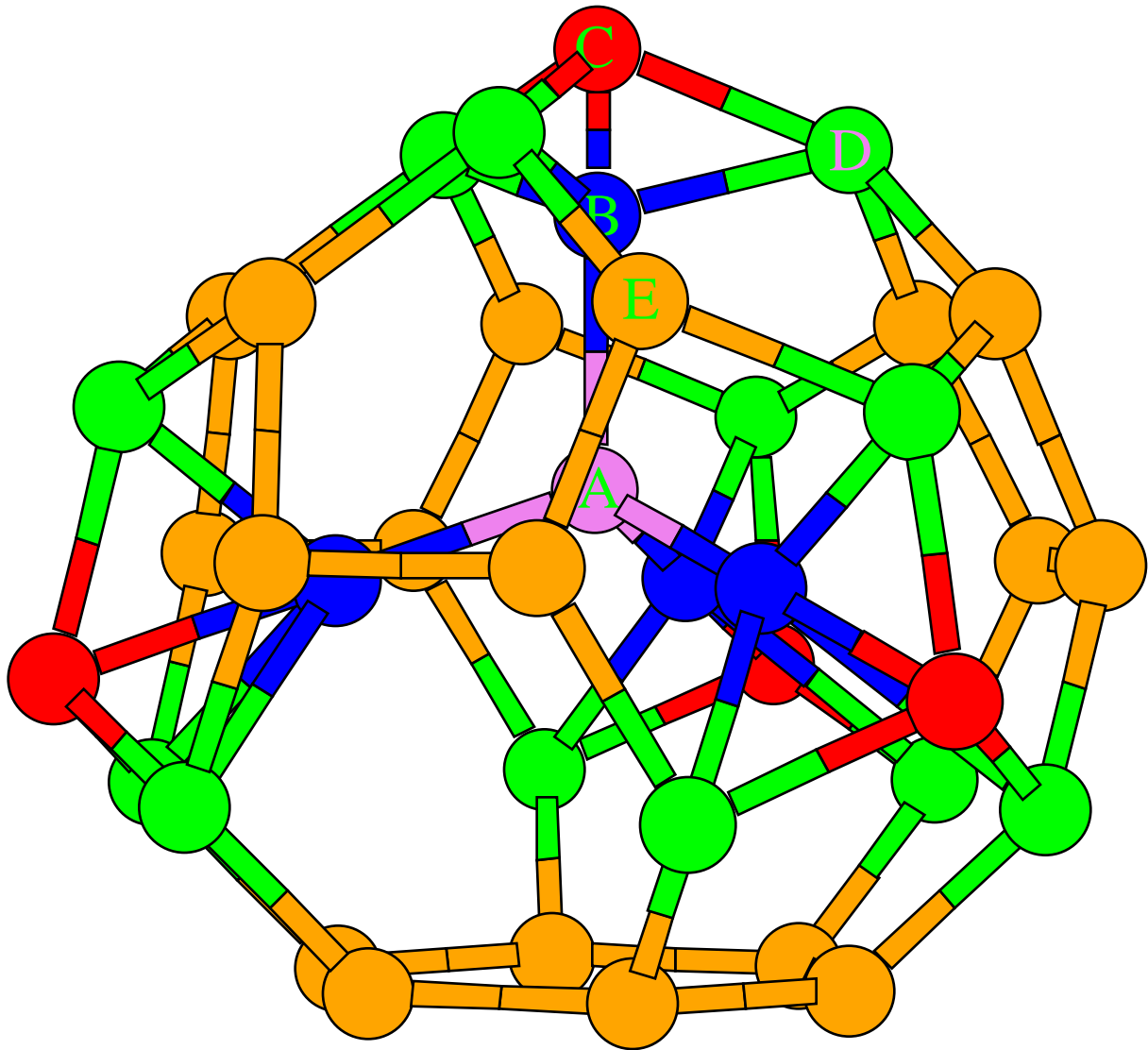
FIGURES

FIG. 1. Structures of Si_{33} , Si_{39} , and Si_{45} clusters obtained using the proposed stuffed fullerene model. The atoms in different chemical environments are colored differently from violet to red, while only the representative atoms are labelled from A to E. These clusters do not possess any dangling bonds and hence are least reactive towards the closed shell reagents ammonia, methanol, ethylene, and water.

Si₃₃



Si₃₉



Si₄₅

